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### 3.23 Electrical, Optical, and Magnetic Properties of Materials

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# Homework \# 12 - Solutions 

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## 1 Average lifetime of excited carriers.

a) As time goes by, electrons excited in the conduction band and holes excited in the valence band relax to lower energy states, causing the photoluminescence spectrum to shift down to smaller energies.
b) When $T=0$, the occupation factor is equal to 1 up to the Fermi level, and sharply drops to 0 above the Fermi level. In this case, the density of excited carriers is simply linked to the Fermi level through the formula (p. 101),

$$
\begin{equation*}
E_{F}^{c}=\frac{\hbar^{2}}{2 m_{e}^{*}}\left(3 \pi^{2} N_{e}\right)^{\frac{2}{3}} \tag{1}
\end{equation*}
$$

So, by substituting the numerical values,

$$
\begin{gathered}
E_{F}^{c}=\frac{\left(1.05 \times 10^{-34}\right)^{2}}{2 \times 0.039 \times 9.11 \times 10^{-31}} \times\left(3 \pi^{2} \times 2 \times 10^{24}\right)^{\frac{2}{3}} \\
E_{F}^{c}=2.36 \times 10^{-20} J=0.145 \mathrm{eV}
\end{gathered}
$$

c) We apply the same equation for holes, but have to be a little careful dealing with the two bands. The total number of holes, $N_{t o t}$, is the sum of $N_{h h}$ and $N_{l h}$, respectively the numbers of heavy and light holes. As a result of Equation (1) applied to each kind, we have,

$$
\begin{aligned}
& 3 \pi^{2} N_{h h}=\left(\frac{2 m_{h h} E_{F}^{v}}{\hbar^{2}}\right)^{\frac{3}{2}} \\
& 3 \pi^{2} N_{l h}=\left(\frac{2 m_{l h} E_{F}^{v}}{\hbar^{2}}\right)^{\frac{3}{2}}
\end{aligned}
$$

Adding those two lines,

$$
3 \pi^{2} N_{t o t}=\left(\frac{2 E_{F}^{v}}{\hbar^{2}}\right)^{\frac{3}{2}}\left(m_{h h}^{\frac{3}{2}}+m_{l h}^{\frac{3}{2}}\right)
$$

Therefore, we get the hole Fermi energy as,

$$
E_{F}^{v}=\frac{\hbar^{2}}{2\left(m_{h h}^{\frac{3}{2}}+m_{l h}^{\frac{3}{2}}\right)^{\frac{2}{3}}}\left(3 \pi^{2} N_{t o t}\right)^{\frac{2}{3}}
$$

$$
E_{F}^{v}=0.0125 \mathrm{eV}
$$

Note: The analytical expression of the reduced mass $\mu$ is a result of the derivation. Here we find $\mu=\left(m_{h h}^{\frac{3}{2}}+m_{l h}^{\frac{3}{2}}\right)^{\frac{2}{3}}$, which is different from the usual $1 / \mu=1 / m_{1}+1 / m_{2}$.
d) In order to know whether the carriers are degenerate, we have to compare $k_{B} T$ with the Fermi level. For $T=180 \mathrm{~K}, k_{B} T=0.015 \mathrm{eV}$. This is of the order of $E_{F}^{v}$ and much smaller than $E_{F}^{c}$. So, the electrons are degenerate, but not the holes.
e) $E_{g}+E_{F}^{c}$ may be read from the spectrum at about 0.95 eV as the point where the luminescence falls to $50 \%$ of its peak value. Since $E_{g} \sim 0.81 \mathrm{eV}$, this yields $E_{F}^{c}=0.14 \mathrm{eV}$, which is close to what we found in question b).
f) Using the same graphical method at 250 ps , we find $E_{F}^{c}=0.04 \mathrm{eV}$. Then,

$$
N_{250}=\frac{1}{3 \pi^{2}}\left(\frac{2 m_{e} E_{F}^{c}}{\hbar^{2}}\right)^{\frac{3}{2}}=2.83 \times 10^{23} m^{-3}
$$

The number of excited carriers follows an exponential decay law,

$$
N(t)=N_{0} e^{-\frac{t}{\tau}}
$$

Therefore,

$$
\tau=\frac{t}{\ln \left(N_{0} / N_{250}\right)}=\frac{250 \mathrm{ps}}{\ln \left(\frac{2 \times 10^{24}}{2.83 \times 10^{23}}\right)}=0.13 \mathrm{~ns}
$$

## 2 Laser oscillation.

a) A simple light emitting diode only uses spontaneous luminescence, when the laser effect is based on stimulated emission.
b) The formula for the reflectivity is,

$$
R=\left[\frac{n-1}{n+1}\right]^{2}
$$

where $n$ is the refractive index. So here,

$$
R=\left[\frac{1.76-1}{1.76+1}\right]^{2}=7.6 \%
$$

c) The frequency separation of the longitudinal modes is,

$$
\frac{c}{2 n l}=\frac{3 \times 10^{8}}{2 \times 1.76 \times 0.1}=8.5 \times 10^{8} \mathrm{~Hz}
$$

d) In the absence of other losses than the ones due to transmission at the ends of the rod, we simply have,

$$
\gamma_{t h}=-\frac{1}{2 l} \ln \left(R_{1} R_{2}\right)=-\frac{1}{2 \times 0.1} \ln (0.076 \times 0.95)=13.14 m^{-1}
$$

## 3 Power efficiency.

a) If the quantum efficiency is $100 \%$ and there are no losses of any kind, each incoming electron causes an excitation which in turn leads to the stimulated emission of one photon. The number of photons emitted per second is then $\frac{i}{e}=\frac{90 \times 10^{-3}}{1.6 \times 10^{-19}}=5.63 \times 10^{17} \mathrm{~s}^{-1}$, and each photon carries an energy equal to $\frac{c}{\lambda} h=\frac{3 \times 10^{8}}{800 \times 10^{-9}} \times 6.63 \times 10^{-34}=2.49 \times 10^{-19} \mathrm{~J}$. Therefore, the output power is $5.63 \times 10^{17} \times 2.49 \times 10^{-19}=140 \mathrm{~mW}$.
b) $\frac{45}{1.8 \times 90}=27.8 \%$.
c) Now introducing a threshold current,

$$
\begin{gathered}
P_{o u t}=\eta \frac{h \nu}{e}\left(I_{\text {in }}-I_{t h}\right) \\
\eta=\frac{P_{\text {out }} \frac{e}{h \nu}}{I_{\text {in }}-I_{t h}}=48 \%
\end{gathered}
$$

